

SCES749B-SEPTEMBER 2009-REVISED MARCH 2010

# LOW-POWER DUAL SCHMITT-TRIGGER INVERTER

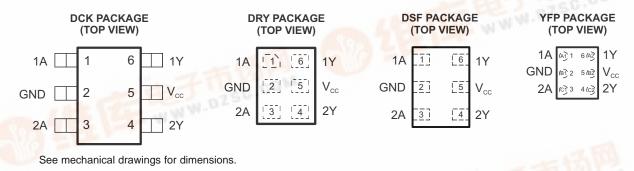
Check for Samples: SN74AUP2G14

### FEATURES

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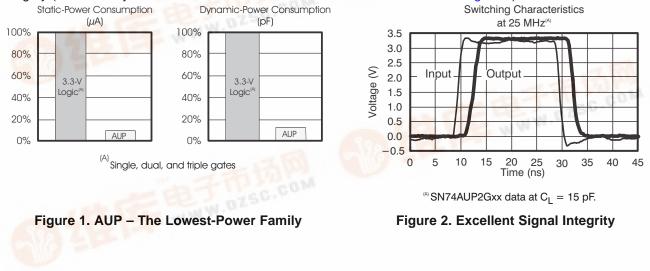
- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I<sub>CC</sub> = 0.9 μA Maximum)
- Low Dynamic-Power Consumption (C<sub>pd</sub> = 4.3 pF Typical at 3.3 V)
- Low Input Capacitance (C<sub>i</sub> = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V<sub>CC</sub>
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V

- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t<sub>pd</sub> = 4.3 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)



## **DESCRIPTION/ORDERING INFORMATION**

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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The SN74AUP2G14 contains two inverters and performs the Boolean function  $Y = \overline{A}$ . The device functions as two independent inverters, but because of Schmitt action, it may have different input threshold levels for positive-going ( $V_{T_{+}}$ ) and negative-going ( $V_{T_{-}}$ ) signals.

NanoStar<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING	INFORMATION <sup>(1)</sup> <sup>(2)</sup>
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T <sub>A</sub>	PACKAGE		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
	NanoStar™  – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP2G14YFPR	HF_
–40°C to 85°C	QFN – DSF	Reel of 5000	SN74AUP2G14DSFR	H6
	uQFN – DRY	Reel of 5000	SN74AUP2G14DRYR	H6
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP2G14DCKR	H6_

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

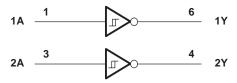
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

#### FUNCTION TABLE (Each Inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

#### LOGIC DIAGRAM (POSITIVE LOGIC)



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#### SCES749B-SEPTEMBER 2009-REVISED MARCH 2010

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	4.6	V	
Vo	Voltage range applied to any output in the I	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>		4.6	V	
Vo	Output voltage range in the high or low stat	e <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA	
lo	Continuous output current			±20	mA	
	Continuous current through $V_{CC}$ or GND			±50	mA	
		DCK package		252		
0	De alve se the sec al impedance (3)	DSF package		300	°C/W	
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>	DRY package		234	-C/W	
		ye in the high or low state <sup>(2)</sup> $V_{I} < 0$ ht $V_{O} < 0$ current through V <sub>CC</sub> or GND pedance <sup>(3)</sup> DCK package DSF package DRY package YFP package		132		
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

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#### **RECOMMENDED OPERATING CONDITIONS**<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		0.8	3.6	V
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.8 V		-20	μA
		V <sub>CC</sub> = 1.1 V		-1.1	
	1 Path land and an end of the	V <sub>CC</sub> = 1.4 V		-1.7	
I <sub>OH</sub>	Input voltage Output voltage High-level output current Low-level output current	V <sub>CC</sub> = 1.65		-1.9	mA
		V <sub>CC</sub> = 2.3 V		-3.1	
		$V_{CC} = 3 V$		-4	
	Input voltage Output voltage High-level output current Low-level output current	V <sub>CC</sub> = 0.8 V		20	μA
		V <sub>CC</sub> = 1.1 V		1.1	
	Level and a device a summer of	V <sub>CC</sub> = 1.4 V		1.7	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9	mA
		V <sub>CC</sub> = 2.3 V		3.1	
		$V_{CC} = 3 V$		4	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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#### SCES749B-SEPTEMBER 2009-REVISED MARCH 2010

#### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v	TA	= 25°C	T <sub>A</sub> = -40°C	C to 85°C	UNIT		
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP MAX	MIN	МАХ	UNIT		
		0.8 V	0.3	0.6	0.3	0.6			
N/		1.1 V	0.53	0.9	0.53	0.9			
V <sub>T+</sub> Positive-going		1.4 V	0.74	1.11	0.74	1.11	V		
input threshold		1.65 V	0.91	1.29	0.91	1.29			
voltage		2.3 V	1.37	1.77	1.37	1.77			
		3 V	1.88	2.29	1.88	2.29			
		0.8 V	0.1	0.6	0.1	0.6			
V <sub>T-</sub>		1.1 V	0.26	0.65	0.26	0.65	V		
v <sub>T-</sub> Negative-going		1.4 V	0.39	0.75	0.39	0.75			
input threshold		1.65 V	0.47	0.84	0.47	0.84			
voltage		2.3 V	0.69	1.04	0.69	1.04			
		3 V	0.88	1.24	0.88	1.24			
		0.8 V	0.07	0.5	0.07	0.5			
		1.1 V	0.08	0.46	0.08	0.46			
ΔV <sub>T</sub>		1.4 V	0.18	0.56	0.18	0.56	V		
Hysteresis (V <sub>T+</sub> – V <sub>T–</sub> )		1.65 V	0.27	0.66	0.27	0.66			
		2.3 V	0.53	0.92	0.53	0.92			
		3 V	0.79	1.31	0.79	1.31			
	I <sub>OH</sub> = -20 μA	0.8 V to 3.6 V	V <sub>CC</sub> – 0.1		V <sub>CC</sub> – 0.1				
_	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>		0.7 × V <sub>CC</sub>				
	I <sub>OH</sub> = -1.7 mA	1.4 V	1.11		1.03				
V <sub>OH</sub>	I <sub>OH</sub> = -1.9 mA	1.65 V	1.32		1.3		V		
	I <sub>OH</sub> = -2.3 mA	2.2.1/	2.05		1.97				
	I <sub>OH</sub> = -3.1 mA	2.3 V	1.9		1.85				
	I <sub>OH</sub> = -2.7 mA	3 V	2.72		2.67				
	$I_{OH} = -4 \text{ mA}$	5 V	2.6		2.55				
	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V		0.1		0.1			
	I <sub>OL</sub> = 1.1 mA	1.1 V		$0.3 \times V_{CC}$		$0.3 \times V_{CC}$			
	I <sub>OL</sub> = 1.7 mA	1.4 V		0.31		0.37			
M.	I <sub>OL</sub> = 1.9 mA	1.65 V		0.31		0.35	V		
V <sub>OL</sub>	I <sub>OL</sub> = 2.3 mA	2.3 V		0.31		0.33	v		
	I <sub>OL</sub> = 3.1 mA	2.3 V		0.44		0.45			
	I <sub>OL</sub> = 2.7 mA	2 \/		0.31		0.33			
	$I_{OL} = 4 \text{ mA}$	3 V		0.44		0.45			
II A or B input	$V_I = GND$ to 3.6 V	0 V to 3.6 V		0.1		0.5	μA		
loff	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}$	0 V		0.2		0.6	μA		
ΔI <sub>off</sub>	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.6	μΑ		
I <sub>cc</sub>	$V_{I} = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_{O} = 0$	0.8 V to 3.6 V		0.5		0.9	μA		
∆I <sub>CC</sub>	$V_{\rm I} = V_{\rm CC} - 0.6 \ V^{(1)}, \ I_{\rm O} = 0$	3.3 V		40		50	μA		
	$V_1 = V_{CC}$ or GND	0 V		1.5					
C <sub>i</sub>		3.6 V		1.5			pF		

(1) One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

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#### **ELECTRICAL CHARACTERISTICS (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T <sub>A</sub> = 25°C			$T_A = -40^{\circ}C$	UNIT	
		V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
Co	V <sub>O</sub> = GND	0 V		3				pF

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 5 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	FROM	то	V	T,	₄ = 25°C	;	T <sub>A</sub> = −40°C t	o 85°C	UNIT							
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT								
			0.8 V		18												
t <sub>pd</sub> A		Y	1.2 V ± 0.1 V	2.6	7.3	12.8	2.1	15.6									
	^		V	V	v	V	V	V	v	v	1.5 V ± 0.1 V	1.4	5.2	8.7	0.9	10.3	20
	A		1.8 V ± 0.15 V	1	4.2	6.6	0.5	8.2	ns								
			2.5 V ± 0.2 V	1	3	4.4	0.5	5.5									
			3.3 V ± 0.3 V	1	2.4	3.5	0.5	4.3									

#### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 10 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	то	v	T,	₄ = 25°C	;	T <sub>A</sub> = −40°C t	to 85°C	UNIT						
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX								
t <sub>pd</sub> A			0.8 V		18.4											
	X	1.2 V ± 0.1 V	4.6	7.9	13.4	1.3	16.7									
		Y	V	V	v	v	v	v	V	v	1.5 V ± 0.1 V	4	6	9.6	2.2	11.8
	A		1.8 V ± 0.15 V	3.6	5	7.9	2.4	9.5	ns							
			2.5 V ± 0.2 V	3.2	4	5.5	2.3	6.8								
			3.3 V ± 0.3 V	2.9	3.5	4.6	2.1	5.6								

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	PARAMETER FROM TO	то	V	$T_{A} = 25^{\circ}$		;	T <sub>A</sub> = -40°C to 85°C		UNIT
FARAINETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	МАХ	UNIT
			0.8 V		24				
		Y	1.2 V ± 0.1 V	3.6	9.9	16.3	3.1	19.9	
	А		1.5 V ± 0.1 V	2.3	7.2	11.1	1.8	13.2	20
τ <sub>pd</sub>	A		1.8 V ± 0.15 V	1.6	5.8	8.7	1.1	10.6	ns
			2.5 V ± 0.2 V	1	4.3	5.9	0.5	7.3	
			3.3 V ± 0.3 V	1	3.4	4.8	0.5	5.9	

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#### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	v <sub>cc</sub> –	T,	ק = 25°C	;	T <sub>A</sub> = −40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		32.8				
			1.2 V ± 0.1 V	4.9	13.1	20.9	4.4	25.5	
	А		1.5 V ± 0.1 V	3.4	9.5	14.2	2.9	16.9	20
t <sub>pd</sub>	A	ř	1.8 V ± 0.15 V	2.5	7.7	11	2	13.5	ns
			2.5 V ± 0.2 V	1.8	5.7	7.6	1.3	9.4	
			3.3 V ± 0.3 V	1.5	4.7	6.2	1	7.5	

### **OPERATING CHARACTERISTICS**

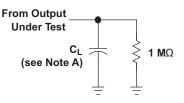
 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
	PARAMETER           C <sub>pd</sub> Power dissipation capacitance		0.8 V	4	
			1.2 V ± 0.1 V	4	
C	f = 10 MHz	1.5 V ± 0.1 V	4	pF	
C <sub>pd</sub>	Power dissipation capacitance	T = 10 WHZ	1.8 V ± 0.15 V	4	рг
			2.5 V ± 0.2 V	4.1	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	4.3	



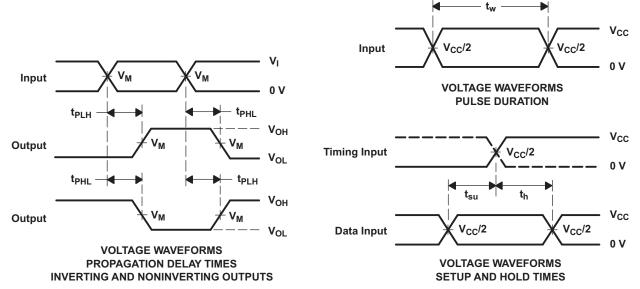
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#### PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = 1.8 V ± 0.15 V	$V_{CC}$ = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
VM	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VI	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>

LOAD CIRCUIT



- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ , for propagation delays  $t_r/t_f = 3$  ns, for setup and hold times and pulse width  $t_r/t_f = 1.2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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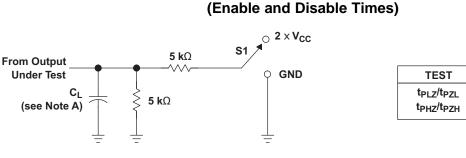


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S1 2 × V<sub>CC</sub>

GND

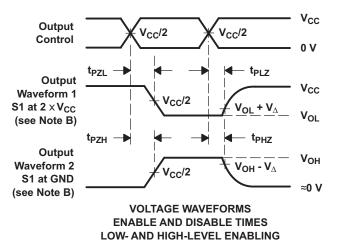
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LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = 1.8 V ± 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VI	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
$V_{\Delta}$	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V

PARAMETER MEASUREMENT INFORMATION



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub>/t<sub>f</sub> = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



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#### **PACKAGING INFORMATION**

Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Pe
ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260
ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260
ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260
ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260
	ACTIVE ACTIVE ACTIVE	ACTIVE     SC70       ACTIVE     SON       ACTIVE     SON	ACTIVE     SC70     DCK       ACTIVE     SON     DRY       ACTIVE     SON     DSF	ACTIVE     SC70     DCK     6       ACTIVE     SON     DRY     6       ACTIVE     SON     DSF     6	ACTIVESC70DCK63000ACTIVESONDRY65000ACTIVESONDSF65000	Drawing         ACTIVE       SC70       DCK       6       3000       Green (RoHS & no Sb/Br)         ACTIVE       SON       DRY       6       5000       Green (RoHS & no Sb/Br)         ACTIVE       SON       DRY       6       5000       Green (RoHS & no Sb/Br)         ACTIVE       SON       DSF       6       5000       Green (RoHS & no Sb/Br)         ACTIVE       SON       VFP       6       3000       Green (RoHS & no Sb/Br)	Drawing     Ball Finish       ACTIVE     SC70     DCK     6     3000     Green (RoHS & CU NIPDAU & no Sb/Br)       ACTIVE     SON     DRY     6     5000     Green (RoHS & NIPDAU & no Sb/Br)       ACTIVE     SON     DSF     6     5000     Green (RoHS & NIPDAU & no Sb/Br)       ACTIVE     SON     DSF     6     5000     Green (RoHS & CU NIPDAU & no Sb/Br)       ACTIVE     DSBGA     YFP     6     3000     Green (RoHS & SNAGCU

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www. information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retard in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

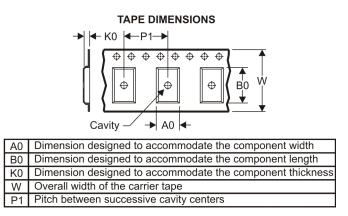
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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G14DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AUP2G14DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP2G14DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q2
SN74AUP2G14YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1



# PACKAGE MATERIALS INFORMATION

20-Jul-2010



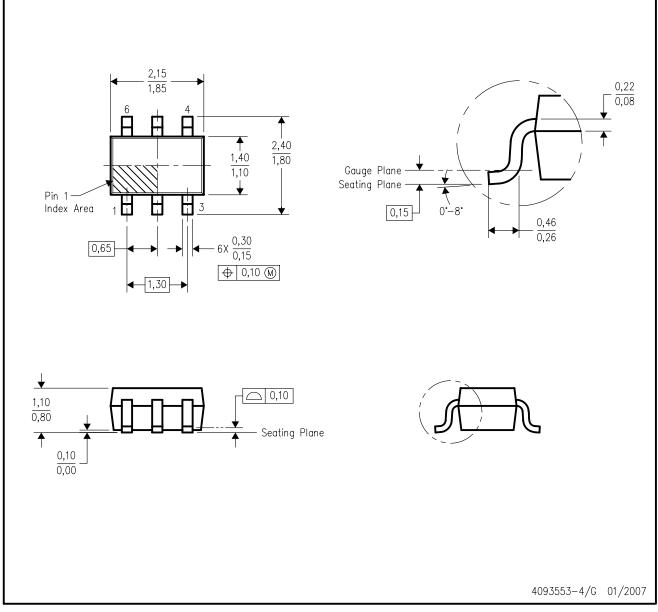
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G14DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74AUP2G14DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP2G14DSFR	SON	DSF	6	5000	202.0	201.0	28.0
SN74AUP2G14YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0

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DCK (R-PDSO-G6)

# PLASTIC SMALL-OUTLINE PACKAGE



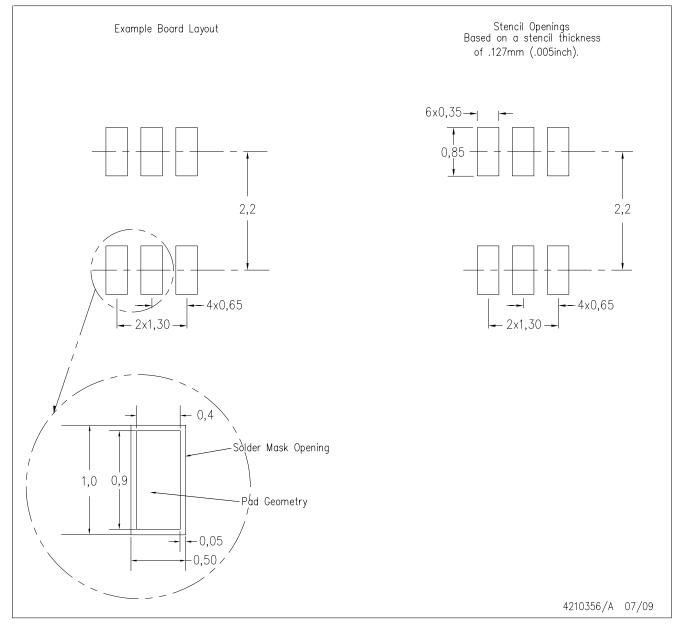
- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AB.



# LAND PATTERN

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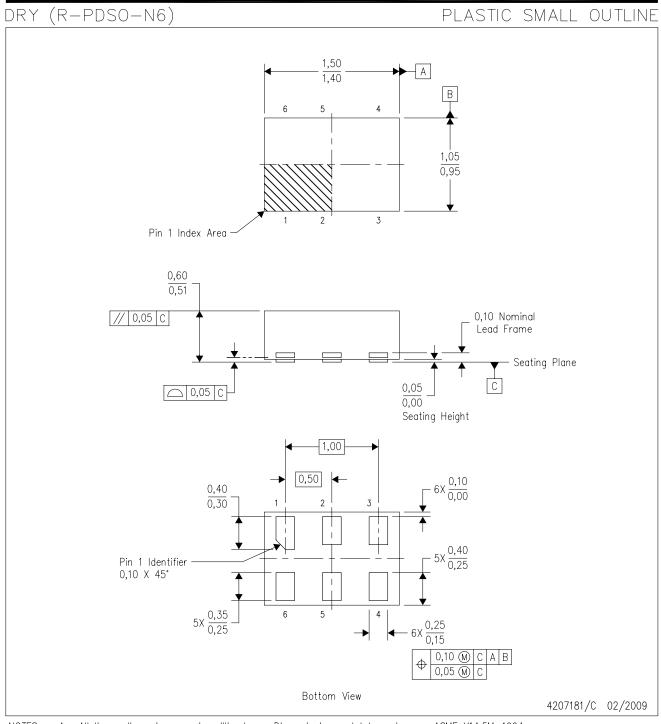
NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



# **MECHANICAL DATA**

# 查询"SN74AUP2G14"供应商



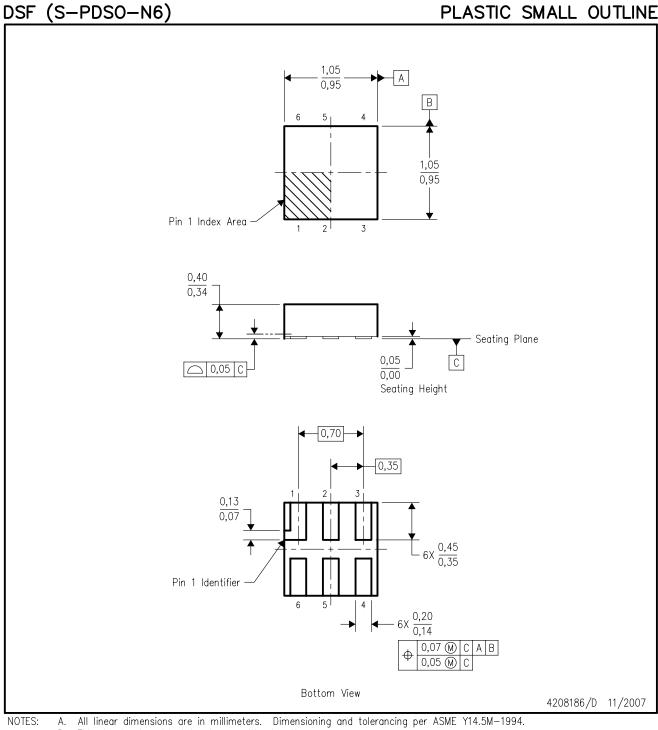
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
   B. This drawing is subject to change without notice.
  - B. This drawing is subject to change without notice.C. SON (Small Outline No-Lead) package configuration.
  - D. This package complies to JEDEC MO-287 variation UFAD.



# **MECHANICAL DATA**

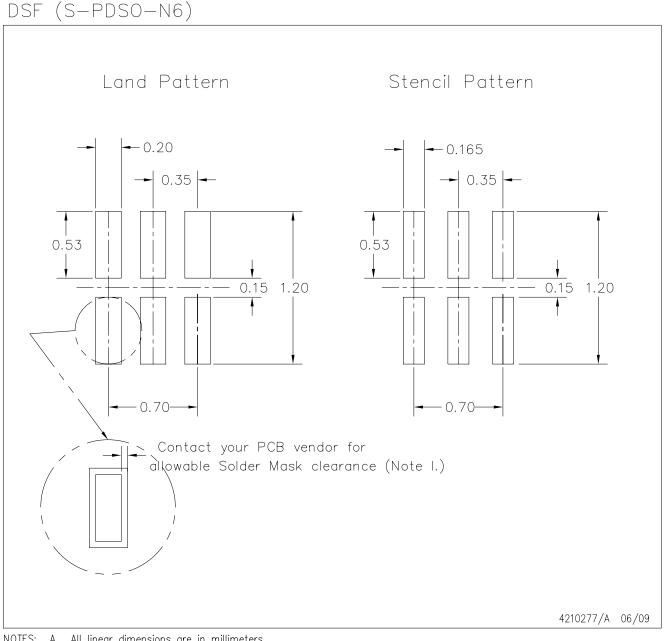
## 查询"SN74AUP2G14"供应商



- B. This drawing is subject to change without notice.
  C. SON (Small Outline No-Lead) package configuration.
  D. This package complies to JEDEC M0-287 variation X2AAF.



# 查询"SN74AUP2G14"供应商



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Over-printing land for acceptable area ratio is not viable due to land width and bridging potential. Customer may further reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
- H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- I. Component placement force should be minimized to prevent excessive paste block deformation.

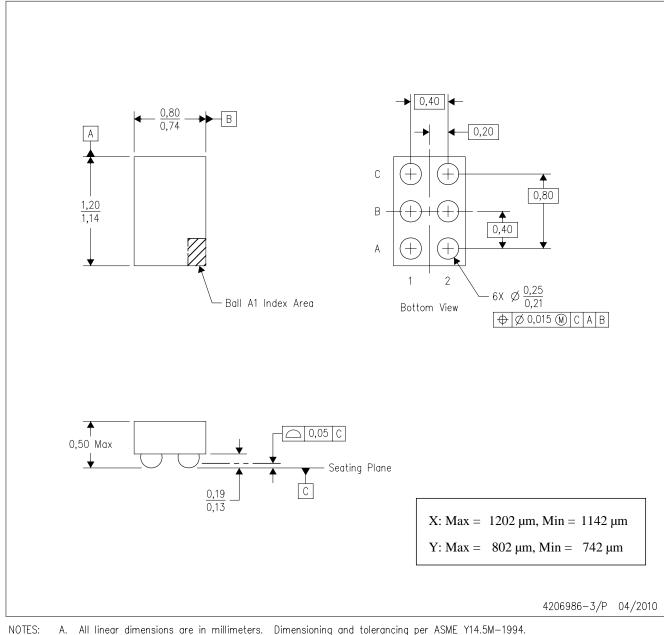


# **MECHANICAL DATA**

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# YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.
  - D. This is a Pb-free solder ball design.

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